Low Power Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V Supply.
- Operating current less than 4mA.
- Low power CMOS design.
- Input frequency range: 13MHz to 30MHz
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: ±1.75% (Typ) @14.7MHz
 Input Frequency.
- Available in 6-pin TSOT-23, 8-pin SOIC and 8pin TSSOP packages.

Product Description

The ASM3P2775A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2775A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2775A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2775A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

The ASM3P2775A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation'.

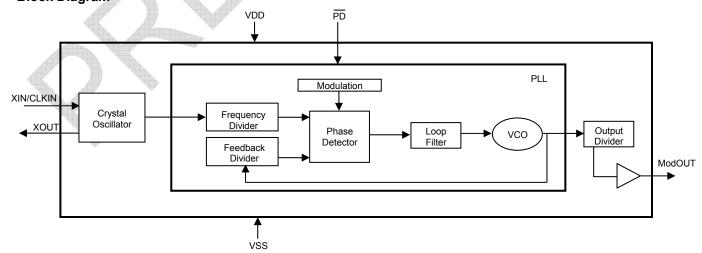
Applications

The ASM3P2775A is targeted towards all portable devices with very low power requirements like MP3 players and digital still cameras.

Key Specifications

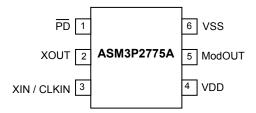
Description	Specification
Supply voltages	VDD = 3.3V ± 0.3V
Cycle-to-Cycle Jitter	200pS (Max)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F _{IN} /640
Frequency Deviation	±1.75% (Typ) @ 14.7MHz

Block Diagram





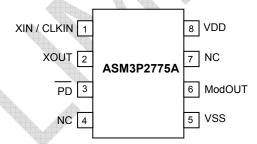
Pin Configuration (6-pin TSOT- 23 Package)



Pin Description

Pin#	Pin Name	Туре	Description
1	PD	I	Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used.
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.
3	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.
4	VDD	Р	Power supply for the entire chip.
5	ModOUT	0	Spread spectrum clock output.
6	VSS	Р	Ground connection.

Pin Configuration (8-pin SOIC and TSSOP Package)

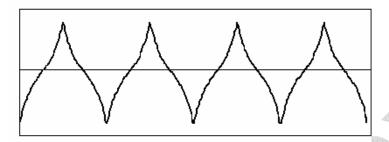


Pin Description

Pin#	Pin Name	Type	Description
1	XIN/CLKIN		Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.
3	PD		Power-down control pin. Pull low to enable power-down mode. Connect to VDD if not used.
4	NC	-	No connect.
5	VSS	Р	Ground connection.
6	ModOUT	0	Spread spectrum clock output.
7	NC	-	No connect.
8	VDD	Р	Power supply for the entire chip.



rev 0.3 Modulation Profile



Specifications

Description	Specification
Frequency Range	13MHz < CLKIN < 30MHz
Modulation Equation	F _{IN} /640
Frequency Deviation	±1.75% (Typ) @ 14.7MHz

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
VDD, V _{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	٧
T _{STG}	Storage temperature	-65 to +125	°C
T _A	Operating temperature	-40 to +85	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
T_J	Junction Temperature	150	°C
T_DV	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV

Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.



DC Electrical Characteristics

(Test condition: All parameters are measured at room temperature (+25°C) unless otherwise stated)

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input low voltage	VSS - 0.3	_	0.8	V
V _{IH}	Input high voltage	2.0	_	VDD + 0.3	V
I _{IL}	Input low current	_	_	-35	μA
I _{IH}	Input high current	_	_	35	μA
I _{XOL}	XOUT output low current (@0.4V, VDD=3.3V)	_	3		mA
I _{XOH}	XOUT output high current (@2.5V, VDD=3.3V)	_	3	- 1	mA
V _{OL}	Output low voltage (VDD = 3.3 V, I _{OL} = 8 mA)	_	4-	0.4	V
V _{OH}	Output high voltage (VDD = 3.3 V, I _{OH} = 8 mA)	2.5	4		V
I _{DD}	Static supply current*	-		10	uA
Icc	Dynamic supply current (3.3V, 16MHz and no load)	_	3.5	-	mA
VDD	Operating voltage	3.0	3.3	3.6	V
t _{ON}	Power-up time (first locked cycle after power-up)**		-	5	mS
Z _{OUT}	Output impedance	A - A	45	_	Ω

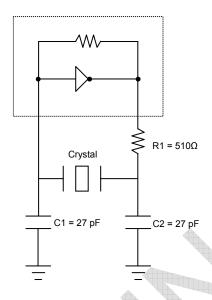
^{**} VDD and XIN/CLKIN input are stable, PD pin is made high from low.

AC Electrical Characteristics

Symbol	Parameter			Тур	Max	Unit	
CLKIN	Input frequency		13	_	30	MHz	
ModOUT	Output frequency		13	_	30	MHz	
f _d	Frequency Deviation	Input Frequency = 13MHz	_	±1.8%	-	. %	
¹d	Input	Input Frequency = 30MHz	_	±1.1%	ı	70	
t _{LH} *	Output rise time (measured from 0.8 to 2.0V)		0.5	1.1	1.3	nS	
t _{HL} *	Output fall time (measured at 2.0V to 0.8V)			0.8	1.0	nS	
t _{JC}	Jitter (cycle to cycle)		-	200	-	pS	
t_D	Output duty cycle		45	50	55	%	
*t _{LH} and t _{HL} are measured into	*t _{LH} and t _{HL} are measured into a capacitive load of 15pF						



Typical Crystal Oscillator Circuit



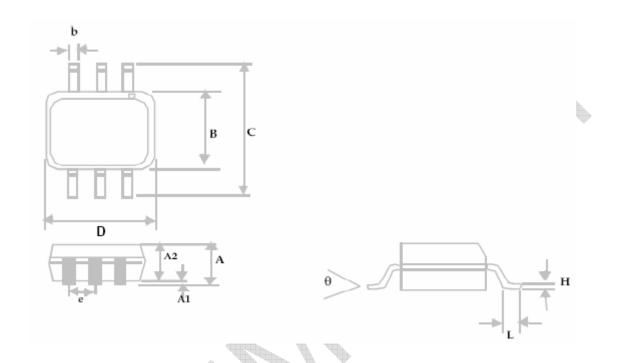
Typical Crystal Specifications

Witchest Technologies	0000 40000					
Fundamental AT cut parallel resonant crystal	Fundamental AT cut parallel resonant crystal					
Nominal frequency	14.31818MHz					
Frequency tolerance	± 50 ppm or better at 25°C					
Operating temperature range	-25°C to +85°C					
Storage temperature	-40°C to +85°C					
Load capacitance	18pF					
Shunt capacitance	7pF maximum					
ESR	25 Ω					



Package Information

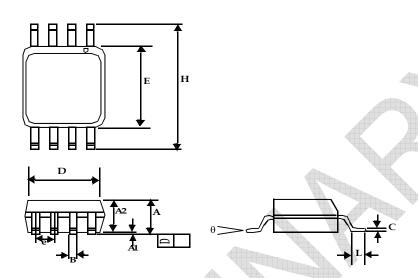
6-pin TSOT-23 Package



	Dimensions			
Symbol	Inches		Millimeters	
	Min	Max	Min	Max
A		0.04		1.00
A1	0.00	0.004	0.00	0.10
A2	0.033	0.036	0.84	0.90
b	0.012	0.02	0.30	0.50
Н	0.005	BSC	0.127 BSC	
D	0.114	BSC	2.90 BSC	
В	0.06	BSC	1.60	BSC
е	0.0374	4 BSC	0.950	BSC
С	0.11 BSC		2.80 BSC	
L	0.0118 0.02		0.30	0.50
θ	0°	4°	0°	4°



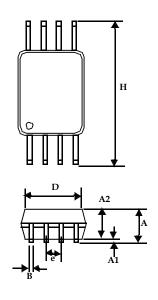
8-Pin SOIC Package

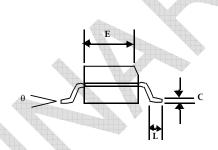


	Dimensions			
Symbol	Inches		Millim	neters
	Min	Max	Min	Max
A1	0.004	0.010	0.10	0.25
А	0.053	0.069	1.35	1.75
A2	0.049	0.059	1.25	1.50
В	0.012	0.020	0.31	0.51
С	0.007	0.010	0.18	0.25
D	0.193	BSC	4.90 BSC	
E	0.154	BSC	3.91 BSC	
е	0.050	BSC	1.27 BSC	
Н	0.236 BSC		6.00 BSC	
L	0.016 0.050		0.41	1.27
θ	0°	8°	0°	8°



8-Pin TSSOP Package





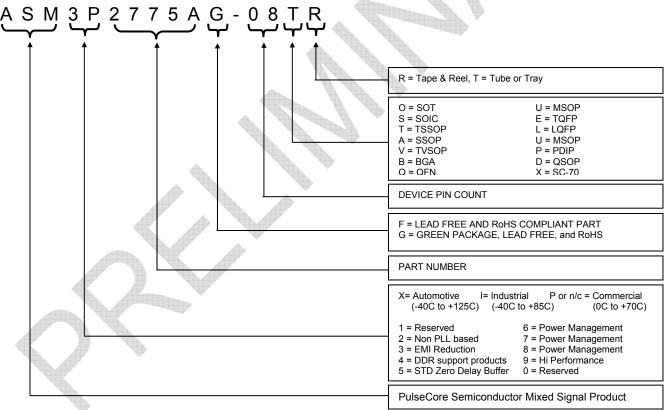
	Dimensions			
Symbol	Inches		Millimeters	
	Min	Max	Min	Max
A		0.043		1.10
A1	0.002	0.006	0.05	0.15
A2	0.033	0.037	0.85	0.95
В	0.008	0.012	0.19	0.30
С	0.004	0.008	0.09	0.20
D	0.114	0.122	2.90	3.10
E	0.169	0.177	4.30	4.50
е	0.026	BSC	0.65	BSC
Н	0.252 BSC		6.40 BSC	
L	0.020	0.028	0.50	0.70
θ	0°	8°	0°	8°



rev 0.3
Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3P2775AF-06OR	X4LL	6-Pin TSOT-23, TAPE & REEL, Pb Free	Commercial
ASM3P2775AF-08TT	3P2775AF	8-Pin TSSOP, TUBE, Pb Free	Commercial
ASM3P2775AF-08TR	3P2775AF	8-Pin TSSOP, TAPE & REEL, Pb Free	Commercial
ASM3P2775AF-08ST	3P2775AF	8-Pin SOIC, TUBE, Pb Free	Commercial
ASM3P2775AF-08SR	3P2775AF	8-Pin SOIC, TAPE & REEL, Pb Free	Commercial
ASM3P2775AG-06OR	X3LL	6-Pin TSOT-23, TAPE & REEL, Green	Commercial
ASM3P2775AG-08TT	3P2775AG	8-Pin TSSOP, TUBE, Green	Commercial
ASM3P2775AG-08TR	3P2775AG	8-Pin TSSOP, TAPE & REEL, Green	Commercial
ASM3P2775AG-08ST	3P2775AG	8-Pin SOIC, TUBE, Green	Commercial
ASM3P2775AG-08SR	3P2775AG	8-Pin SOIC, TAPE & REEL, Green	Commercial

Device Ordering Information



Licensed under U.S Patent Nos 5,488,627 and 5,631,921





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Fax: 408-879-9018 www.pulsecoresemi.com Copyright © Alliance Semiconductor All Rights Reserved Preliminary Information Part Number: ASM3P2775A Document Version: v0.3

Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003

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